

EXG

1

9 kHz to 3 or 6 GHz

Data Sheet

Anticipate ____Accelerate ____Achieve



Agilent Technologies

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Optimized for manufacturing

On the path to faster throughput and greater uptime, the costeffective EXG X-Series signal generators are optimized for manufacturing test. With analog and vector models, the EXG provides the signals you'll need for basic parametric testing of components and functional verification of receivers. Get "just enough" test at the right price with the EXG.

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Definitions and Conditions

Specifications describe the performance of parameters covered by the product warranty and apply to the full temperature range of 0 to 55 $^{\circ}$ C, unless otherwise noted.

Typical describes additional product performance information that is not covered by the product warranty. It is performance beyond specifications that 80 percent of the units exhibit with a 95 percent confidence level over the temperature range 20 to 30 °C. Typical performance does not include measurement uncertainty.

Nominal values indicate expected performance, or describe product performance that is useful in the application of the product, but are not covered by the product warranty.

Measured describes an attribute measured during the design phase for purposes of communicating expected performance, such as amplitude drift vs. time. This data is not warranted and is measured at room temperature (approximately 25 °C).

The generator will meet its specifications when it has been stored at an ambient temperature within the allowed operating range for at least two hours before being turned on or if it had previously been stored at a temperature range inside the allowed storage range, but outside the allowed operating range.

Frequency Specifications

Frequency range			
Frequency range	Option 501 (N5171B only)	9 kHz to 1 GHz	
	Option 503	9 kHz to 3 GHz	
	Option 506	9 kHz to 6 GHz	
Resolution	0.01 Hz		
Phase offset	Adjustable in nominal 0.1 ° inc	crements	
Frequency bands ¹			
	Band	Frequency range	Ν
	1	9 kHz to < 5 MHz	Digital synthesis
	1	5 to < 250 MHz	1
	2	250 to < 375 MHz	0.25
	3 375 to < 750 MH		0.5
	4	750 to < 1500 MHz	1
	5	1500 to < 3000.001 MHz	2
	6	3000.001 to 6000 MHz	4
Frequency switching speed ^{2, 3}			
	Standard	Option UNZ ⁴	Option UNZ, typical
CW mode			
SCPI mode	≤ 5 ms, typical	≤ 1.15 ms	≤ 950 µs
List/step sweep mode	≤ 5 ms, typical	≤ 900 µs	≤ 800 µs
Digital modulation on (N5172B only			
SCPI mode	≤ 5 ms, typical	≤ 1.15 ms	≤ 1.05 ms
List/step sweep mode	≤ 5 ms, typical	≤ 900 µs	≤ 800 µs

1. N is a factor used to help define certain specifications within the document.

2. Time from receipt of SCPI command or trigger signal to within 0.1 ppm of final frequency or within 100 Hz, whichever is greater, and amplitude settled to within 0.2 dB from 20 to 30 °C. Implies simultaneous frequency and amplitude switching.

3. With internal channel corrections on, the frequency switching speed is < 1.3 ms, measured for list mode and SCPI mode cached frequency points. For the initial frequency point in SCPI mode the time is < 3.3 ms, measured. The instrument will automatically cache the most recently used 1024 frequencies. There is no speed degradation for amplitude-only changes.

4. Specifications apply when status register updates are off.

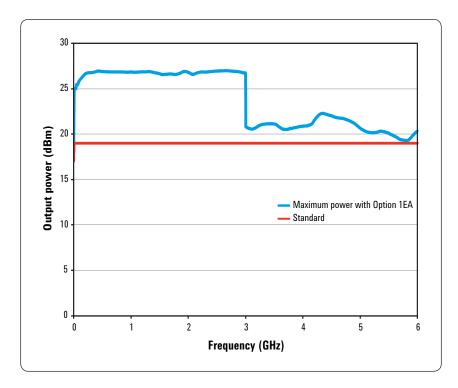
Frequency reference	
Accuracy	± aging rate ± temperature effects ± line voltage effects
Internal time base reference oscillator aging rate ¹	$\leq \pm 5$ ppm/10 yrs, $\leq \pm 1$ ppm/yr, nominal
Adjustment resolution	< 1 x 10^-10, nominal
Temperature effects	± 1 ppm (0 to 55 °C), nominal
Line voltage effects	± 0.1 ppm, nominal; 5% to –10%, nominal
Reference output	
Frequency	10 MHz
Amplitude	\geq +4 dBm, nominal into 50 Ω load
External reference input	
Input frequency, standard	10 MHz
Input frequency, Option 1ER	1 to 50 MHz (in multiples of 0.1 Hz)
Lock range	± 1 ppm
Amplitude	> -3.0 to 20 dBm, nominal
Impedance	50 Ω, nominal
Waveform	Sine or square
Sweep modes (frequency and amplitude)	
Operating modes	Step sweep (equally spaced frequency and amplitude or logarithmically spaced frequency steps) List sweep (arbitrary list of frequency and amplitude steps) Simultaneously sweep waveforms with N5172B; see Baseband Generator section for more detail
Sweep range	Within instrument frequency range
Dwell time	100 µs to 100 s
Number of points	2 to 65535 (step sweep) 1 to 3201 (list sweep)
Step change	Linear or logarithmic
Triggering	Free run, trigger key, external, timer, bus (GPIB, LAN, USB)

1. Aging rate is determined by design as a function of the TCXO.

Amplitude Specifications

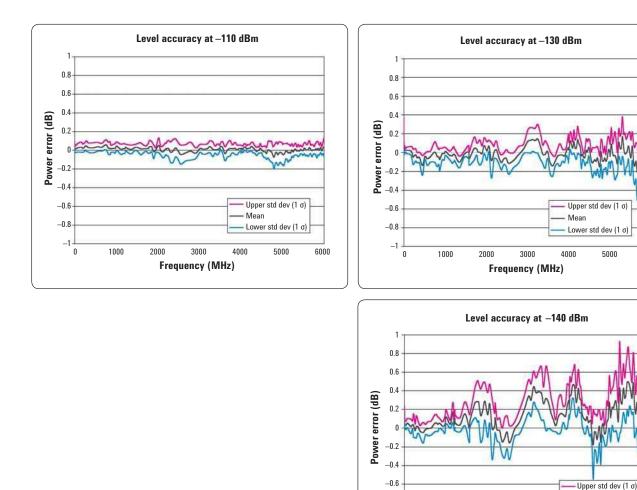
Output parameters			
Settable range	+30 to -144 dBm		
Resolution	0.01 dB, nominal		
Step attenuator	0 to 130 dB in 5 dB ste	os electronic type	
Connector	Type N 50 Ω, nominal		
Max output power ¹			
ινίαλ σατράτ ρόννει			
Frequency	Standard	Option 1EA	
	Standard +13 dBm	Option 1EA +17 dBm	
Frequency		-	

1. Quoted specifications between 20 °C and 30 °C. Maximum output power typically decreases by 0.01 dB/°C for temperatures outside this range.



Absolute level accuracy in CW mode ¹ (ALC on)							
External reference input	+21 to -60 dBm < -60 to -110 dBm < -110 to -127 dBm						
9 to 100 kHz	± 0.6 dB, typical	± 0.6 dB, typical ± 0.9 dB, typical					
100 kHz to 5 MHz	± 0.8 dB	± 0.8 dB ± 0.9 dB					
> 5 MHz to 3 GHz	± 0.6 dB ± 0.8 dB ± 0.5 dB, typical						
> 3 to 6 GHz	± 0.6 dB ± 1.1 dB ± 0.6 dB, typical						
Absolute level accuracy in CW mode (ALC off, power search run, relative to ALC on)							
9 kHz to 6 GHz ± 0.15 dB, typical							
Absolute level accuracy in digital I/Q mode (N5172B only)							
(ALC on, relative to CW, W-CDMA 1 DPCH configuration $< +10$ dBm)							
9 kHz to 6 GHz ± 0.25 dB							

1. Quoted specifications between 20 °C and 30 °C. For temperatures outside this range, absolute level accuracy degrades by 0.01 dB/°C. Output power may drift up to .003 dB per g/kg change in absolute humidity (nom).



6000

Mean

4000

Lower std dev (1 σ)

5000

6000

www.valuetronics.com

-0.8

-1

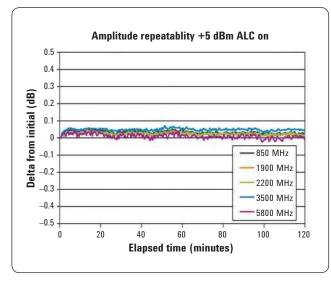
0

1000

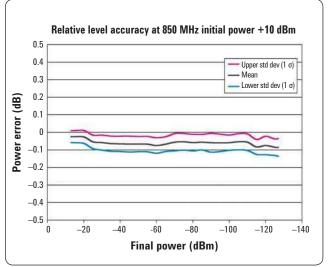
2000

3000

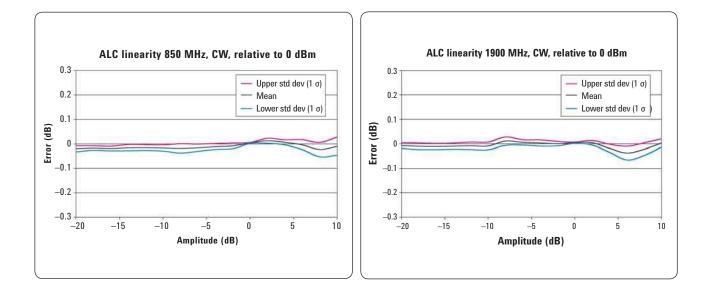
Frequency (MHz)



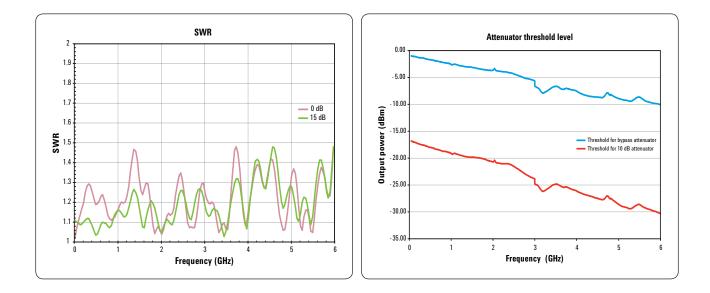
Repeatability measures the ability of the instrument to return to a given power setting after a random excursion to any other frequency and power setting. It should not be confused with absolute level accuracy.



Relative level accuracy measures the accuracy of a step change from any power level to any other power level. This is useful for large changes (such as 5 dB steps).



SWR (measured CW mode)					
F	Attenuator state				
Frequency	Bypass	0 to 10 dB	15 dB or more		
≤ 1.0 GHz	< 1.3:1	< 1.35:1	< 1.2:1		
> 1.0 to 2 GHz	< 1.55:1	< 1:5:1	< 1.3:1		
> 2 to 3 GHz	< 1.9:1	< 1.4:1	< 1.3:1		
> 3 to 4 GHz	< 1.5:1	< 1.6:1	< 1.45:1		
> 4 to 6 GHz	< 1.8:1	< 1.6:1	< 1.6:1		

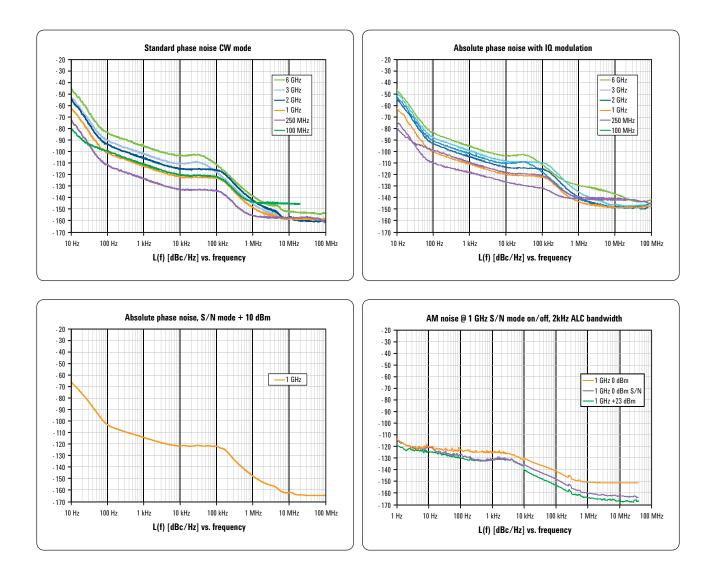


Maximum reverse power, nom	inal				
< 1 GHz	50 W				
> 1 to < 2 GHz	25 W				
> 2 to < 6 GHz	20 W				
Max DC voltage	50 VDC				
Trip level	2 W				
Amplitude switching speed ¹	Standard	Option UNZ	Option UNZ, typical		
CW mode					
SCPI mode	≤ 5 ms, typical	≤ 750 µs	≤ 650 μs		
Power search SCPI mode	< 12 ms, measured				
List/step sweep mode	≤ 5 ms, typical	≤ 500 µs	≤ 300 µs		
Digital modulation on (N5172B only)					
SCPI mode	≤ 5 ms, typical	≤ 1.15 ms	≤ 950 μs		
Power search SCPI mode	< 12 ms, measured				
List/step sweep mode	≤ 5 ms, typical	≤ 900 µs	≤ 400 μs		
Alternate power level control	(N5172B only)				
Switching time (via waveform markers)	20 µs within ± 1 dB, mea	sured			
Functional power range	-15 dBm to -144 dBm, r	neasured			
User flatness correction					
Number of points	3201				
Number of tables	Dependent on available f	Dependent on available free memory in instrument; 10,000 maximum			
Entry modes	USB/LAN direct power meter control, LAN to GPIB and USB to GPIB, remote bus and manual USB/GPIB power meter control				
Sweep modes					
	See Frequency Specificat	tions section for more detail			

1. Time from receipt of SCPI command or trigger signal to amplitude settled within 0.2 dB. Switching speed specifications apply when status register updates are off.

Spectral Purity Specifications

Absolute SSB phase noise (dBc/Hz, CW at 20 kHz offset, typical)			
249 MHz	-119		
250 MHz	-133		
500 MHz	-128		
1 GHz	-122		
2 GHz	-115		
3 GHz	-110		
4 GHz	-109		
6 GHz	-103		



Harmonics (CW mode)		
Range	Standard < +4 dBm	Option 1EA < +12 dBm
9 kHz to 3 GHz	<-35 dBc	<-30 dBc
> 3 to 4 GHz	<–35 dBc, typical	<–35 dBc, typical
> 4 to 6 GHz	< –53 dBc, typical	< –40 dBc, typical
Nonharmonics (CW mode)		
Range	> 10 KHz offset	
	Standard (dBc)	
9 kHz to < 5 MHz	–65, nominal	
5 to < 250 MHz	-75	
250 to < 750 MHz	-75	
750 MHz to < 1.5 GHz	-72	
1.5 to < 3.0 GHz	-66	
3 to 6 GHz	-60	

Subharmonics (CW mode)				
9 kHz to 1.5 GHz	None			
> 1.5 to 3 GHz	—82 dBc			
> 3 to 6 GHz	—74 dBc			
Jitter ¹				
Carrier frequency	SONET/SDH data rate	rms jitter BW	μUI rms, measured	Seconds, typical
155 MHz	155 MB/s	100 Hz to 1.5 MHz	140	0.9 ps
622 MHz	622 MB/s	1 KHz to 5 MHz	67	0.11 ps
2.488 GHz	2488 MB/s	5 kHz to 20 MHz	271	0.11 ps
Phase coherence (Option 012)				
LO input frequency range	250 MHz to 6 GHz, nomi	nal		
LO input power range	0 to +7 dBm, nominal			
LO output frequency range	250 MHz to 6 GHz, nominal			
LO output power range	0 to +7 dBm, nominal			

1. Calculated from phase noise performance in CW mode at +10 dBm. For other frequencies, data rates, or bandwidths, please consult your sales representative.

Analog Modulation Specifications

Band #	Frequency range	N		
1	9 kHz to <5 MHz	1 (digital synthesis)		
1	5 to < 250 MHz	1		
2	250 to < 375 MHz	0.25		
3	375 to < 750 MHz	0.5		
4	750 to < 1500 MHz	1		
5	1500 to < 3000.001 MHz	2		
6	3000.001 to 6000 MHz	4		
Frequency modulation (Option UI	NT) (See N value above)			
Max deviation	N × 10 MHz, nominal			
Resolution	0.1% of deviation or 1 Hz, whichever	is greater, nominal		
Deviation accuracy	$< \pm 2\% + 20$ Hz (1 kHz rate, deviation	n is N x 50 kHz)		
Nodulation frequency response	1 dB bandwidth	DC/5 Hz to 3 MHz, nominal		
o 100 KHz rate	3 dB bandwidth	DC/1 Hz to 7 MHz, nominal		
Carrier frequency accuracy	$< \pm 0.2\%$ of set deviation + (N \times 1 Hz	z) ¹		
Relative to CW in DCFM	$< \pm 0.06\%$ of set deviation + (N \times 1 H	$< \pm 0.06\%$ of set deviation + (N \times 1 Hz), typical ²		
Distortion	< 0.4% [1 kHz rate, deviation is N x 5	< 0.4% [1 kHz rate, deviation is N x 50 kHz]		
M using external inputs 1 or 2	Sensitivity	+1 V peak for indicated deviation, nomina		
	Input impedance	50 Ω/600 Ω/1 M Ω, nominal		
	Paths	FM path 1 and FM path 2 are summed internally for composite modulation		
Phase modulation (Option UNT)	(See N value above)			
Maximum deviation	Normal bandwidth	N × 5 radians, nominal		
	High-bandwidth mode	N × 0.5 radians, nominal		
requency response	Normal bandwidth (3 dB)	DC to 1 MHz, nominal		
	High-bandwidth mode (3 dB)	DC to 4 MHz, nominal		
Resolution	0.1% of deviation			
Deviation accuracy	< + 0.5% + 0.01 rad, typical [1 kHz ra	te, normal bandwidth mode]		
Distortion	< 0.2% (typ) [1 kHz rate, deviation no	rmal bandwidth mode]		
ΦM using external inputs 1 or 2	Sensitivity	+1 V peak for indicated deviation, nomina		
	Input impedance	50 Ω or 600 Ω or 1 M Ω, nominal		
		ΦM path 1 and ΦM path 2 are summed		

1. Specification valid for temperature changes of less than ± 5 °C since last DCFM calibration.

2. Typical performance immediately after a DCFM calibration.

Amplitude modulation (Opti	on UNT)1					
AM depth type	Linear or expon	ential				
Maximum depth	100%					
Depth resolution	0.1% of depth (nom)				
AM depth error	f < 5 MHz		< 1.5% of setti	ng + 1% (typ 0.5%	% of setting + 1%	5)
@1 KHz rate and < 80% depth	$5 \text{ MHz} \le f \le 2 \text{ G}$	θHz	< 3% of setting	g + 1 %		
	2 < f < 3 GHz		< 5% of setting	g + 1% (typical 3%	% of setting + 1%	5)
Total harmonic distortion			30% depth	< 0.25%, typica	al	
@ 1 KHz rate	F < 5 MHz		80% depth	< 0.5%, typical		
	$5 \text{ MHz} \le f < 2 \text{ G}$ (2 to 3 GHz is ty		30% depth	< 2%		
			80% depth	< 2%		
Frequency response	30% depth, 3 dE	3 BW	DC/10 Hz to 5	0 KHz		
AM inputs using external inputs 1 or 2	Sensitivity		+1 V peak for i 2.2 V peak)	indicated depth(Over-range can b	oe 200% or
	Input impedanc	е	50 Ω or 600 Ω	or 1M Ω, Damage	e level: ± 5 V max	(
	Paths	Paths AM path 1 and AM path 2 are summed internally for composi modulation				y for composite
Wideband AM (N5172B only)	Rates ALC off/o	on	DC/800 Hz to	60 MHz, nominal		
	Sensitivity		0.25 V = 100%	(I input + 0.5 V o	offset)	
	Input impedanc	е	50 Ω , nominal	(l input)		
Simultaneous and composit	e modulation ²					
Simultaneous modulation	except: FM and simultaneously	phase modulati generated using and FM can run	on cannot be cor y the same modu	e modulation) ma nbined and two n lation source; for d all will modulate	nodulation types example, the bas	cannot be seband I/Q
Composite modulation				on paths which ar ombination of int		
	АМ	FM	Phase	Pulse	Internal IQ ²	External IQ ²
AM	+	+	+	+	+	+
FM	+	+	_	+	+	+
Phase	+	_	+	+	+	+
Pulse	+	+	+	-	+	+
Internal I/Q ²	+	+	+	+	*	+
External IQ ²	+	+	+	+	+	-
+ = compatible, - = incompatible,	* = Internal + Ext	ernal				

 1. AM specifications apply 6 dB below maximum specified power from 20 to 30 °C.

2. IQ modulation available on N5172B.

ulation inputs; Option UNW required for pulse modulation inputs) AM, FM, PM
AM, FM, FM AM, FM, PM
Pulse (50 Ω only)
Wideband AM (50 Ω only, N5172B only)
50 Ω, 1 MΩ, 600 Ω, DC and AC coupled
phase modulation requires Option UNT or 303) Sine
0.1 Hz to 2 MHz (tunable to 3 MHz) 0.1 Hz
Same as RF reference source, nominal
0 to 5 V peak into 50 $\Omega,$ –5V to 5 V offset, nominal
onsists of seven waveform generators that can be set independently with up to fiv eatures in AM, FM/PM, and LF out
Sine, triangle, square, positive ramp, negative ramp (pulse for LF out only)
Sine, triangle, square, positive ramp, negative ramp (pulse for LF out only)
Sine, triangle, square, positive ramp, negative ramp, phase offset, and amplitud ratio for Tone 2 relative to Tone 1
Sine, triangle, square, positive ramp, negative ramp Trigger: free run, trigger key, bus, external, internal, timer trigger
Uniform, Gaussian
Uniform, Gaussian
Only for LF output –5 V to +5 V, nominal
0.1 Hz to 10 MHz, nominal
0.1 Hz to 1 MHz, nominal
10 MHz, nominal
0.1 Hz
Same as RF reference source, nominal
> 80 dB, typical
< 10 ns; 7 ns, typical
\geq 2 us/ \geq 20 ns
10 Hz to 500 kHz/DC to 10 MHz
< ± 1.0 dB/< ± 1.0 dB, typical

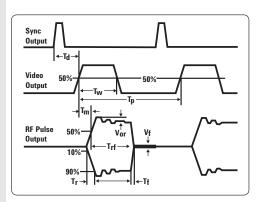
1. Pulse specifications apply to frequencies > 500 MHz. Operable down to 10 MHz.

2. With power search on.

Video feed-through $^{1} \leq 3$ GHz/> 3 GHz	< 50 mV, typical/< 5 mV, typical
Video delay (ext input to video)	30 ns, nominal
RF delay (video to RF output)	20 ns, nominal
Pulse overshoot	< 15%, typical
Input level	+1 Vpeak = RF on into 50 Ω , nominal

Td video delay (variable) Tw video pulse width (variable) Tp pulse period (variable) Tm RF delay Trf RF pulse width Tf RF pulse fall time Tr RF pulse rise time Vor pulse overshoot

. Vf Video feedthrough



Internal pulse generator (included w	ith Option UNW)					
Modes	Free-run, square, trig external pulse	Free-run, square, triggered, adjustable doublet, trigger doublet, gated, and external pulse				
Square wave rate	0.1 Hz to 10 MHz, 0.	1 Hz resolution, nominal				
Pulse period	30 ns to 42 seconds	, nominal				
Pulse width	20 ns to pulse period	d –10 ns, nominal				
Resolution	10 ns					
Adjustable trigger delay	-pulse period + 10 r	-pulse period + 10 ns to pulse period to pulse width -10 ns				
Settable delay	Free run	-3.99 to 3.97 μs				
	Triggered	0 to 40 s				
Resolution (delay, width, period)	10 ns, nominal					
Pulse doublets	1st pulse delay	(Relative to sync out) 0 to 42 s – pulse width – 10 ns				
	1st pulse width	500 ns to 42 s – delay – 10 ns				
	2nd pulse delay	0 to 42 s – (Delay 1 + Width 2) – 10 ns				
	2nd pulse width	20 ns to 42 s – (Delay 1 + Delay 2) – 10 ns				
Pulse train generator Option 320 (rec	quires Option UNW)					
Number of pulse patterns	2047					

Number of pulse patterns On/off time range

20 ns to 42 sec

FREQUENCY	Â	MPLITUDE	Train Display
6.000 00	000000 GHz	-10.00 dBm	Time Offset 0.00000000
	PULSE		sec
Time Offset: 0.000			Zoom In
	Pulse Train		
Forestantestantestantest	(*		Zoom Out
Osec	1.00usec/div	4.90use	c Zoom In Max
			Zoom Out Max
** PROTO CODE ** NOT FI		05/19/2010 09:4	

1. Video feed through applies to power levels < +10 dBm.

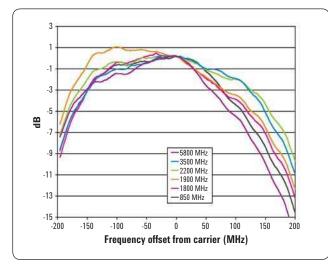
Vector Modulation Specifications

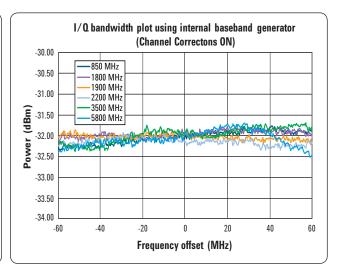
N5172B only

I/Q modulator external inputs ¹		
Bandwidth	Baseband (I or Q)	Up to 100 MHz baseband, nominal
	RF (I+Q)	Up to 200 MHz RF, nominal
l or Q offset	± 100 mV	
I/Q gain	± 1 dB	
Quadrature angle adjustment	± 200 units	
Full scale input drive (I+Q)	0.5 V into 50 Ω, nominal	
Internal I/Q baseband generator a	ljustments ² (Options 653	and 655)
I/Q offset	± 20%	(0.025% dB resolution)
I/Q gain	±1dB	(0.001 dB resolution)
Quadrature angle adjustment	± 10 °	(0.01 degrees resolution)
I/Q phase	± 360.00 °	(0.01 degrees resolution)
I/Q skew	± 500 ns	(1 picosecond resolution)
l/Q delay	± 250 ns	(1 picosecond resolution)
External I/Q outputs		
Impedance	50 Ω , nominal per output	
	100 Ω , nominal differential o	utput
Туре	Single-ended or differential ((Option 1 EL)
Maximum voltage per output	± 0.5 V peak-to-peak; into 50) Ω (200 uV resolution)
Bandwidth	Baseband (I or Q)	60 MHz, nominal (Option 653 and 655)
	RF (I+Q)	120 MHz, nominal (Option 653 and 655)
Amplitude flatness	± 0.2 dB measured with cha	nnel corrections optimized for IQ output
Phase flatness	± 2.5 degrees measured with	h channel corrections optimized for IQ output
Common mode I/Q offset	± 1.5 V into 50 Ω (200 uV res	solution)
Differential mode I or Q offset	± 25 mV into 50 Ω (200 uV re	esolution)

1. I/Q adjustments represent user intverface parameter ranges and not specifications.

2. Internal IQ adjustments apply to RF out and IQ outputs simultaneously.





Channels	2 [l and Q]					
Resolution	16 bits [1/65,536]					
Sample rate	Option 653	100 Sa/s to 75 MSa/s				
	Option 653 and 655	100 Sa/s to 150 MSa/s				
RF bandwidth	Option 653	60 MHz, nominal				
an bandwidth	Option 653 and 655	120 MHz, nominal				
nterpolated DAC rate	800 MHz					
Frequency offset range	± 60 MHz					
Digital sweep modes	In list sweep mode each point in the list can	have independent waveforms (NE172B)				
Signal Sweep modes	along with user definable frequencies and an Specifications sections for more detail.	,				
Naveform switching speed ¹		\leq 5 ms, measured (standard)				
	SCPI mode	\leq 1.2 ms, measured (Option UNZ)				
	Link (stern error model	\leq 5 ms, measured (standard)				
	List/step sweep mode	\leq 900 us, measured (Option UNZ)				
Naveform transfer rates	FTP LAN to internal SSD	10.7 MB/sec or 2.67 Msa/sec				
measured, no markers)	Internal SSD to FTP LAN	7.7 MB/sec 1.92 Msa/sec				
	FTP LAN to BBG	8.2 MB/sec or 2.05 Msa/sec				
	FTP LAN to BBG encrypted	4 MB/sec or 1 Msa/sec				
	USB to BBG	19 MB/sec or 4.75 Msa/sec				
	BBG to USB	1.2 MB/sec or 300 Ksa/sec				
	Internal SSD to BBG	48 MB/sec or 12 Msa/sec				
	BBG to internal SSD	1.2 MB/sec or 300 Ksa/sec				
	Removable SD card to baseband generator (C	Removable SD card to baseband generator (Option 006)				
Arbitrary waveform memory		32 Msa (standard)				
	Maximum playback capacity	256 Msa (Option 021)				
		512 Msa (Option 022)				
		3 GBytes/800 Msa (standard)				
	Maximum storage capacity including markers	30 GBytes/7.5 Gsa (Option 009)				
		8 GBytes / 2 Gsa (Option 006)				
Naveform segments		60 samples to 32 Msa (standard)				
	Segment length	60 samples to 256 Msa (Option 021)				
		60 samples to 512 Msa (Option 022)				
	Minimum memory allocation per segment	256 samples				
	Maximum number of segments	8192				
Naveform sequences	Maximum number of sequences	> 2000 depending on non-volatile memory usage				
		32,000 (standard)				
	Maximum number of segments/sequence	4 million (Option 021 or 022)				
	Maximum number of repetitions	65,535				

1. SCPI mode switching speed applies when waveforms are pre-loaded in list sweep and sample rate \geq 10 MSa/s.

Triggers	Types		Continuous, single, gated, segment advance	
	Source		Trigger key, external, bus (GPIB, LAN, USB)	
		Continuous	Free run, trigger and run, reset and run	
		Single	No retrigger, buffered trigger, immediate retrigger	
	Modes	Gated	Negative polarity or positive polarity	
		Segment advance	Single or continuous	
	External coarse delay	time	5 ns to 40 s	
	External coarse delay		5 ns	
	Trigger latency (Single	trigger only)	356 ns + 1 sample clock period, nominal	
	Trigger accuracy (Sing	le trigger only)	± 2.5 ns, nominal	
Multi-baseband generator	Fan out		1 master and up to 15 slaves	
synchronization mode	Trigger repeatability		< 1 ns, nominal	
(multiple sources)	Trigger accuracy		Same as normal mode	
	Trigger latency		Same as normal mode	
	Fine trigger delay rang	е	See Internal IQ Baseband section	
	Fine trigger delay reso		See Internal IQ Baseband section	
	IQ phase adjustment r		See Internal IQ Baseband section	
Markers	Markers are defined in a segment during the waveform generation process, or from the front panel; a marker can also be routed to the RF blanking, ALC hold functions, and alternate amplitude; see Users Guide for more information			
	Marker polarity		Negative, positive	
	Number of markers		4	
	RF blanking/burst on/off ratio		> 80 dB	
	Alternate amplitude control switching speed		See amplitude section	
Real-time baseband generator ((Option 660)			
Real-time baseband generator required for real-time Signal Studio	Cellular real-time applications		LTE-FDD, LTE-TDD, HSPA+/W-CDMA, GSM/EDGE, cdma2000®	
applications ¹	Real-time navigation		GPS, GLONASS	
	Real-time video applica	tions	DVB-T/T2/H/S/S2/C/J.83 Annex A/C, ISDB-T/	
	Note: Option 660 is not	required for real-time cus	stom modulation (Option 431)	
	Memory: Shares memo	ory with Options 653 and	655	
	Triggering: Same as O	ptions 653 and 655		
	Markers: 3 markers av	vailable, all other featur	es are same as Options 653 and 655	
AWGN (Option 403)				
Туре	Real-time, continuous	ly calculated, and played	using DSP	
Modes of operation	Standalone or digitally a	dded to signal played by a	rbitrary waveform or real-time baseband generato	
Bandwidth	With Option 653		1 Hz to 60 MHz	
	With Option 653 and 6	55	1 Hz to 120 MHz	
Crest factor	15 dB			
Randomness	90 bit pseudo-random	generation, repetition p	eriod 313 x 10^9 years	
Carrier-to-noise ratio	± 100 dB when added			
Carrier-to-noise ratio formats	C/N, Eb/No			
Carrier-to-noise ratio error	Magnitude error ≤ 0.2	dB at baseband I/Q out	puts	

1. See Signal Studio configuration assistant for more information.

Custom modulation Arb	Mode (Option 431)					
Modulation	PSK		BPSK, QPSK, OQPSK, π/4DQPSK, gray coded and unbalanced QPSK, 8PSK, 16PSK, D8PSK			
	QAM		4, 16, 32, 64, 128, 256, 1024 (and 89600 VSA mappings)			
	FSK		Selectable: 2, 4, 8, 16, C4FM			
	MSK		0 to 100 °			
	ASK		0 to 100%			
Multicarrier	Number of ca	rriers	Up to 100 (limited by a max bandwidth of 120 MHz depending on symbol rate and modulation type)			
	Frequency offs	et (per carrier)	Up to60 to +60 MHz			
	Power offset	(per carrier)	0 dB to -40 dB			
Symbol rate	50 sps to 75 M	Vlsps				
Filter types	Nyquist, root-	Nyquist, Gaussian, rectar	ngular, APCO 25 C4EM, user			
Quick setup modes	APCO 25w/C PHS, PWT, TE		<i>Bluetooth</i> [®] , CDPD, DECT, EDGE, GSM, NADC, PDC,			
Data	Random only					
Custom modulation real-	time mode (Option 4	131) (Does not requir	e Option 660)			
Modulation	PSK	BPSK, QPSK, OQF 8PSK, 16PSK, D8I	PSK, π/4DQPSK, gray coded and unbalanced QPSK, PSK			
	QAM	4, 16, 32, 64, 128,	4, 16, 32, 64, 128, 256, 1024 (and 89600 VSA mappings)			
		Selectable	2,4,8, 16 level symmetric, C4FM			
	FSK	User-defined	Custom map of up to 16 deviation levels			
		Max deviation	40 MHz			
	MSK	0 to 100 °				
	ASK	0 to 100%				
	Custom I/Q	Custom map of 1	024 unique values			
Frequency offset	Up to60 MH	Iz to +60 MHz				
Symbol rate	Internal gene	rated data	1000 sps to 75 Msps and max of 10 bits per symbo (Option 653 + 655)			
	External seria	l data	1000 sps to [(50 Mbits/sec)/(#bits/symbol)]			
Filter types	Selectable		Nyquist, root-Nyquist, Gaussian, rectangular, APCO 25 C4FM, IS-95			
	Custom FIR		16-bit resolution, up to 64 symbols long, automatically resampled to 1024 coefficients (max) > 32 to 64 symbol filter: symbol rate ≤ 12.5 MHz > 16 to 32 symbol filter: symbol rate ≤ 25 MHz Internal filters switch to 16 tap when symbol rate i between 25 and 75 MHz			
Quick setup modes		4FM, APCO25 w/CQPSK, VT, WorldSpace, Iridium, I	TETRA , Bluetooth, CDPD, DECT, EDGE, GSM, NADC ICO, CT2, TFTS			
Trigger delay	Range		0 to 1,048,575 bits			
	Resolution		1 bit			

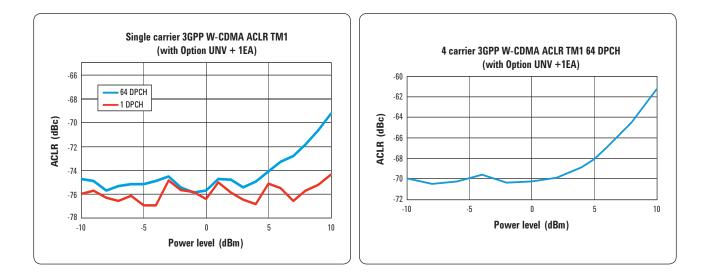
Data types	Internally generated	Pseudo-random patterns	PN9, PN11, PN15, PN20, PN23		
	Internally generated	Repeating sequence	Any 4-bit sequence		
		32 Mb (standard)			
	Direct-pattern RAM [PRAM] Note: Used for custom TDN		512 Mb (Option 021)		
		IA/ IIOII-Stanuaru Iraniniy	1024 Mb (Option 022)		
			32 MB (standard)		
	User file		256 MB (Option 021)		
			512 MB (Option 022)		
		Туре	Serial data		
	Externally streamed data	Inputs/outputs	Data, symbol sync, bit clock (output only)		
Internal burst shape	Rise/fall time range		Up to 30 bits		
(varies with bit rate)	Rise/fall delay range	–15 to +15 bits			
Multitone and two-tone (Option	430)				
Number of tones	2 to 64, with selectable on/o	off state per tone			
Frequency spacing	100 Hz to 120 MHz (with Op	tion 653 and 655)			
Phase (per tone)	Fixed or random				
Real-time phase noise impairme	ents (Option 432)				
Close-in phase noise characteristics	–20 dB per decade				
Far-out phase noise characteristics	–20 dB per decade				
Mid-frequency characteristics	Start frequency (f1)	Offset settable from 0 to 77	MHz		
	Stop frequency (f2)	Offset settable from 0 to 77	MH ₇		
	otop				

FREQUENCY			Phase Noise
	10 000 000 00 GHz	-5.00 dBm	Phase Noise
EXTR Desired f1: 1.00 Stan		Impairment	Desirec Start Freq(f1) 1.000000kHz
-40	f1 f2		Desired Stop Freq(f2) 30.000000kHz
L(f) dBc/Hz		Lmid	Desired Flat Amplitude(Lmid) -70.00 dBc/Hz
-110	Frequency, Log Scale	111Hz	

3GPP W-CDMA distortion performance ^{1,2}								
			Standard		Option U	NV	Option U with Opt	
		\leq 2 dBm ²	2	\leq 2 dBm ²	2	\leq 5 dBm ²	2	
Offset	Configuration	Frequency	Spec	Тур	Spec	Тур	Spec	Тур
Adjacent (5 MHz)		1800 to 2200 MHz	- 69 dBc	-73 dBc	—71 dBc	—75 dBc	—71 dBc	—75 dBc
Alternate (10 MHz)	- 1 DPCH, 1 carrier		—70 dBc	—75 dBc	—72 dBc	–77 dBc	—71 dBc	—77 dBc
Adjacent (5 MHz)	Test model 1 with	1800 to 2200 MHz	68 dBc	-70 dBc	—71 dBc	—73 dBc	—71 dBc	-72 dBc
Alternate (10 MHz)	64 DPCH, 1 carrier			—73 dBc	—72 dBc	76 dBc	—71 dBc	-76 dBc
Adjacent (5 MHz)	Test model 1 with	1800 to 2200 MHz	-63 dBc	-65 dBc	-65 dBc	—67 dBc	64 dBc	-66 dBc
Alternate (10 MHz)	64 DPCH, 4 carrier		64 dBc	-66 dBc	66 dBc	68 dBc	-66 dBc	68 dBc

1. ACPR specifications apply when the instrument is maintained within \pm 20 to 30 °C.

2. This is rms power. Convert from rms to peak envelope power (PEP) with the following equation: PEP = rms power + crest factor (for example, 3GPP test model 1 with 64 DPCH has a crest factor 11.5 dB, therefore at +5 dBm rms, the PEP = 5 dBm + 11.5 dB = +16.5 dBm PEP).

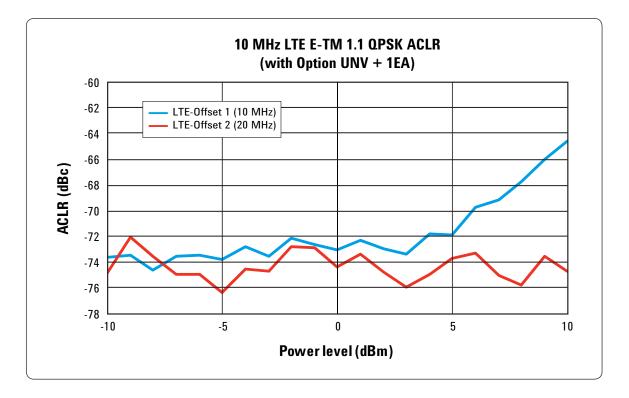


3GPP LTE-FDD distortion performance ¹								
Standard Option UNV					NV	Option U with Opt		
	Power level		\leq 2 dBm ²	2	\leq 2 dBm ²	2	\leq 5 dBm ²	2
Offset	Configuration	Frequency	Spec	Тур	Spec	Тур	Spec	Тур
Adjacent (10 MHz) ³	10 MHz E-TM 1.1	1000 to 2200 MUz	—64 dBc	-66 dBc	—67 dBc	-69 dBc	64 dBc	—67 dBc
Alternate (20 MHz) ³	QPSK	1800 to 2200 MHz	-66 dBc	-68 dBc	69 dBc	—71 dBc	-69 dBc	–71 dBc

1. ACPR specifications apply when the instrument is maintained within \pm 20 to 30 °C.

2. This is rms power. Convert from rms to peak envelope power with the following equation: PEP = rms power + crest factor (for example, 3GPP test model 1 with 64 DPCH has a crest factor 11.5 dB, therefore at +5 dBm rms, the PEP = 5 dBm + 11.5 dB = +16.5 dBm PEP).

3. ACPR measurement configuration: reference channel integration BW: 9.015 MHz, offset channel integration bandwidth: 9.015 MHz.



GSM/EDGE out	put RF spectrum	(ORFS)				
			GSM		EDGE	
Power level			< +7 dBm		< +7 dBm	
Offset	Configuration	Frequency ¹	Standard, typical	Option UNV, typical	Standard, typical	Option UNV, typical
200 kHz			34 dBc	—36 dBc	—37 dBc	38 dBc
400 kHz		000 / 000 MU	—69 dBc	dBc -70 dBc -69 dBc		-70 dBc
600 kHz	 1 normal timeslot, bursted 	800 to 900 MHz 1800 to 1900 MHz	—81 dBc	-82 dBc	80 dBc81 dBc	81 dBc
800 kHz		1000 to 1000 WHZ	82 dBc	—83 dBc	—82 dBc	83 dBc
1200 kHz			84 dBc	—85 dBc	—83 dBc	—84 dBc
3GPP2 cdma200	0 distortion perfo	ormance, typical				
			Standard	Option UNV	Option UNV -	⊦ 1EA
Power level ²		≤ 2dBm	≤ 2 dBm	≤ 5 dBm		
Offset	Configuration	Frequency (1)	Typical	Typical	Typical	
885 kHz to 1.98 MHz	- 0 1 17 1		–78dBc	–79dBc	–77dBc	
> 1.98 to 4.0 MHz	9 channel forward - link	800 to 900 MHz	-86dBc	–87dBc	–87dBc	
> 4.0 to 10 MHz			–91dBc	–93dBc	–93dBc	
802.16e Mobile WiMAX™ distortion performance, measured						
Power	Offset ³	Configuration ⁴	Frequency	Standard, measured	UNV, measur	ed
		QPSK	2.5 and 3.5 GHz	—65 dBc	–68 dBc	
<-7 dBm	10 MHz	UFSK	2.5 and 5.5 0112	00 000	00 000	

1. Performance evaluated at bottom, middle, and top of bands shown.

2. This is rms power. Convert from rms to peak envelope power (PEP) with the following equation: PEP = rms power + crest factor (for example: 3GPP test model 1 with 64 DPCH has a crest factor > 11 dB, therefore at +5 dBm rms the PEP = 5 dBm + 11 dB = +16 dBm PEP).

3. Measurement configuration: reference channel integration BW: 9.5 MHz, offset channel integration BW: 9 MHz, channel offset: 10 MHz.

4. 802.16e WiMAX signal configuration—bandwidth: 10 MHz, FFT: 1024, frame length: 5 ms, guard period: 1/8, symbol rolloff: 5%, content: 30 symbols of PN9 data.

Farmer et						EVM performance data ^{1,2}					
Format	GSM		EDGE		cdma2000/1xEV-DO		W-CDM/	4	LTE FDI) ³	
Modulation type	GMSK (burst	ted)	3pi/8 8PSK (bursted)		QPSK		QPSK		64 QAM		
Modulation rate	270.833 ksps	3	70.833 ksps		1.2288 Mcps		3.84 Mcps		10 MHz BW		
Channel configuration	1 timeslot		1 timeslot	:	Pilot chai	nnel	1 DPCH		E-TM 3.	1	
Frequency ⁴	800 to 900 N 1800 to1900		800 to 900 1800 to 19		800 to 90 1800 to 1	•	1800 to 22	200 MHz	1800 to	2200 MHz	
EVM power level	≤7 dBm		≤7 dBm		≤ 7 dBm ≤ 7		≤7 dBm	≤7 dBm		≤7 dBm	
EVM power level with Option 1EA	≤ 13 dBm		≤ 13 dBm		≤ 13 dBm	1	≤ 13 dBm		≤ 13 dB	m	
EVM/global phase error	Spec	Туре	Spec	Туре	Spec	Туре	Spec	Туре	Me	asured	
	ms 0.8 ° peak 1.5 °	0.2 ° 0.6 °	1.2%	0.75%	1.3%	0.8%	1.2%	0.8%	(0.2%	
Format	802.11a/g	802.16e WiMAX ⁵	QPSK			16 QAM					
Modulation type	64 QAM	64 QAM	QPSK 16 QAM								
Modulation rate	54 Mbps	10 MHz BW	4 Msps (root-Nyquist filter α = 0.25)								
Frequency ⁴	2400 to 2484 MHz 5150 to	2300 to 2690 MHz 3300 to	≤ 3	GHz	≤ 6	GHz	≤ 3	GHz	≤	6 GHz	
	5825 MHz	3800 MHz		10				10		4.15	
EVM power level EVM power level with Option 1EA	<u>≤</u> –5 dBm ≤ 2 dBm	<u>≤ 2 dBm</u> ≤ 8 dBm		dBm dBm		dBm) dBm		dBm dBm		4 dBm 0 dBm	
EVM	Measured	Measured	Spec	Туре	Spec	Туре	Spec	Туре	Spec	Туре	
	0.3%	0.3%	1.2%	0.8%	1.9%	1.1%	1.1%	0.65%	1.5%	0.9%	

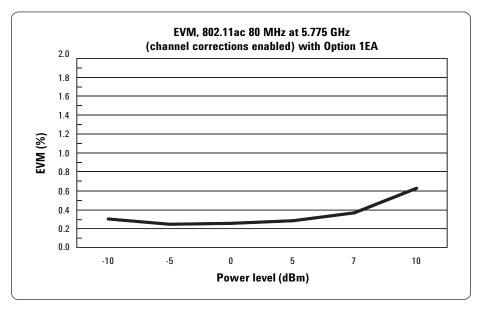
1. EVM specifications apply for the default ARB file setup conditions with the default ARB files supplied with the instrument.

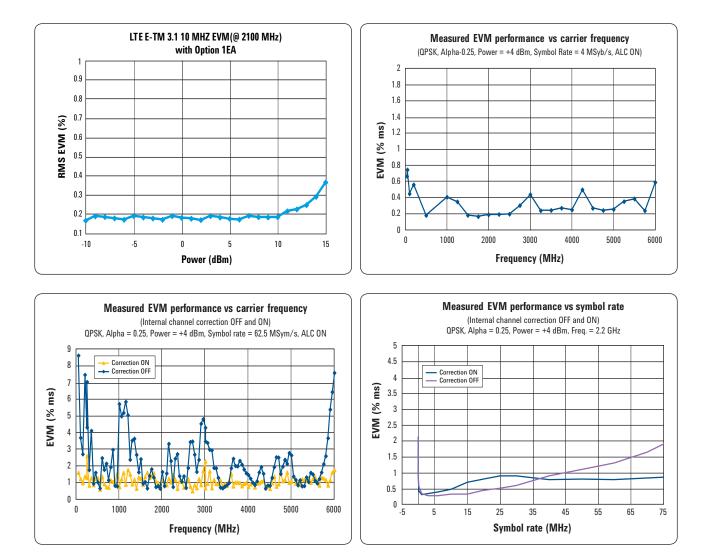
2. EVM specifications apply after execution of I/Q calibration when the instrument is maintained within ± 5 °C of the calibration temperature.

3. LTE FDD E-TM 3.1,10 MHz, 64 QAM PDSCH, full resource block. Measured EVM after DC calibration.

4. Performance evaluated at bottom, middle, and top of bands shown.

5. 802.16e WiMAX signal configuration—bandwidth: 10 MHz, FFT: 1024, frame length: 5 ms, guard period: 1/8, symbol rolloff: 5%, content: 30 symbols of PN9 data.





General Specifications

Remote programming					
Interfaces	GPIB IEEE-488.2, 1987 with liste LAN 1000BaseT LAN interface, I USB Version 2.0				
Control languages	SCPI Version 1997.0				
Compatibility languages	Agilent Technologies: N5181A\61A, N 5182A\62A, N5183A, E4438C, E4428C, E442xB, E443xB, E8241A, E8244A, E8251A, E8254A, E8247C, E8257C/D, E8267C/D, 8648 Series, 8656B, E8663B, 8657A/B				
	Aeroflex Inc.: 3410 Series				
	Rohde & Schwarz: SMB100A, S SMATE200A, SMIQ, SML, SMV	MBV100A, SMA100A, SMU200A, SMJ100A,			
Power requirements					
100-120 VAC, 50/60/400 Hz 220-240 VAC, 50/60 Hz 160 W maximum (N5171B) 300 W maximum (N5172B)					
Operating temperature range					
0 to 55 °C					
Storage temperature range					
–40 to 70 °C					
Operating and storage altitude					
Up to 15,000 feet					
Environmental stress					
against the environmental stresses of stora	ge, transportation and end-use; thos	invironmental Test Manual and verified to be robust se stresses include but are not limited to temperature, aligned with IEC 60068-2 and levels are similar to MIL			
Safety					
Complies with European Low Voltage Direc	tive 2006/95/EC				
 IEC/EN 61010-1, 2nd Edition Canada: CSA C22.2 No. 61010-1 USA: UL std no. 61010-1, 2nd Edition German Acoustic statement 	Acoustic noise emission LpA < 70 dB Operator position Normal position Per ISO 7779	Geraeuschemission LpA < 70 dB Am Arbeitsplatz Normaler Betrieb Nach DIN 45635 t.19			
EMC					
Complies with European EMC Directive 200	4/108/EC				
 IEC/EN 61326-1or IEC/EN 61326-2-1 CISPR Pub 11 Group 1, class A AS/NZS CISPR 11 	CISPR Pub 11 Group 1, class A cet appareil ISM est conforme a la norme NMB-001 du Canada				

ICES/NMB-001

Memory

- · Memory is shared by instrument states, user data files, sweep list files, waveform sequences, and other files
- 2 GB (30 GB with Option 009) memory available in the N5172B
- · Security Option 006 allows storage of up to 8 GB
- · Depending on how the memory is utilized, a maximum of 1000 instrument states can be saved

Security (Option 006)

- Removable 8 GB solid state memory (SD card) from rear panel
- User can force all files to be stored only on external memory card including instrument states, user data files, sweep list files, waveforms, waveform sequences, and other files.
- · Memory sanitizing, memory sanitizing on, power on, and display blanking
- · Disable USB ports

Note: Read/write speeds to external memory card will be slower compared to internal solid-state drive (Option 009)

Self-test

Internal diagnostic routines test most modules in a preset condition; for each module, if its node voltages are within acceptable limits, the module passes the test

Weight

N5171B: \leq 13.6 kg (30 lb) net, \leq 28.6 kg (63 lb.) shipping N5172B: \leq 15.9 kg (35 lb) net, \leq 30.8 kg (68 lb.) shipping

Dimensions

88 mm H x 458 mm W x 508 mm L (3.46 in H x 18 in W x 20 in L)

Recommended calibration cycle

36 months

ISO compliant

This instrument is manufactured in an ISO-9001 registered facility in concurrence with Agilent Technologies' commitment to quality.

Inputs and Outputs

Front panel connectors			
RF output	Outputs the RF signal via a precision N type female connector; see output section for reverse power protection information		
I and Q inputs	BNC input accepts "in-phase" and "quadrature" input signals for I/Q modulation; nominal input impedance is 50 Ω , damage levels are 1 Vrms and 5 Vpeak		
USB 2.0	Used with a memory stick for transferring instrument states, licenses and other files into or out of the instrument; also used with U2000 Series USB average power sensors For a current list of supported memory sticks, visit www.agilent.com/find/X-series_SG, click on Technical Support, and refer to FAQs: Waveform Downloads and Storage		
Rear panel connectors			
Rear panel inputs and outputs are 3.3 V CM voltage levels	OS, unless indicated otherwise; CMOS inputs will accept 5 V CMOS, 3 V CMOS, or TTL		
RF output (Option 1EM)	Outputs the RF signal via a precision N type female connector		
I and Q inputs (Option 1EM)	Accepts "in-phase" and "quadrature" input signals for I/Q modulation SMB connector, nominal input impedance is 50 Ω; damage levels are 1 Vrms and 5 Vpeak; Option 1EM and N5162A units will come with 2 SMB to BNC adapters		
I and Q outputs	BNC outputs the analog I/Q modulation signals from the internal baseband generator; nominal output impedance 50 Ω , DC coupled; damage levels \pm 2 V		
l bar and Q bar outputs (Option 1EL)	BNC outputs the complement of the I and Q signals for differential applications;		
DAC Clk In (Option 012)	Reserved for future use.		
Event 1	This connector outputs the programmable timing signal generated by marker 1 The marker signal can also be routed internally to control the RF blanking and ALC hold functions; this signal is also available on the AUX I/O connector This output is TTL and 3.3 V CMOS compatible Damage levels are > +8 V and < -4 V		
Pattern trigger	Accepts signal to trigger internal pattern generator to start single pattern output, for use with the internal baseband generators Accepts CMOS signal with minimum pulse width of 10 ns Female BNC Damage levels are > +8 V and < -4 V		
BBTRIG 1	Reserved for arbitrary and real-time baseband generators I/O such as Markers or trigger inputs		
BBTRIG 2	Reserved for arbitrary and real-time baseband generators I/O such as Markers or trigger inputs		
Sweep out	Generates output voltage, 0 to +10 V when the signal generator is sweeping; this output can also be programmed to indicate when the source is settled or output pulse video and is TTL and CMOS compatible in this mode; output impedance < 1 Ω , can drive 2 k Ω ; damage levels are ± 15 V		
Ext 1	External AM/FM/PM #1 input; nominal input impedance is 50 $\Omega/600~\Omega/1M~\Omega,$ nominal; damage levels are \pm 5 V		
Ext 2	External AM/FM/PM #2 input; nominal input impedance is 50 $\Omega/600~\Omega$ /1M $\Omega,$ nominal; damage levels are \pm 5 V		
LF OUT	0 to 5 V peak into 50 $\Omega,$ –5 V to 5 V offset, nominal		
Pulse	External pulse modulation input; this input is TTL and CMOS compatible; low logic levels are 0 V and high logic levels are +1 V; nominal input impedance is 50 Ω ; input damage levels are ≤ -0.3 V and $\geq +5.3$ V		

Trigger in	Accepts TTL and CMOS level signals for triggering point-to-point in sweep mode; damage levels are ≤ -0.3 V and $\geq +5.3$ V
Trigger out	Outputs a TTL and CMOS compatible level signal for use with sweep mode The signal is high at start of dwell, or when waiting for point trigger in manual sweep mode, and low when dwell is over or point trigger is received This output can also be programmed to indicate when the source is settled, pulse synchronization, or pulse video Nominal output impedance 50 Ω Input damage levels are ≤ -0.3 V and $\geq +5.3$ V
Reference input	Accepts a 10 MHz reference signal used to frequency lock the internal timebase; Option 1ER adds the capability to lock to a frequency from 1 MHz to 50 MHz; nominal input level –3.5 to +20 dBm, impedance 50 Ω , sine or square waveform
10 MHz out	Outputs the 10 MHz reference signal used by internal timebase; level nominally +3.9 dBm; nominal output impedance 50 Ω ; input damage level is +16 dBm
LO in (Option 012)	Accepts a signal from a master signal generator that is used as the LO for EXG vector in order to configure a phase coherent system; nominal input levels between 0 to +7 dBm; nominal input impedance 50 Ω
LO out (Option 012)	Outputs a reference signal that can be used in a phase coherent system; nominal output levels between 0 to 7 dBm; nominal output impedance 50 Ω
Digital bus I/O	To be used with PXB or N5102A digital signal interface module
Aux IO	50 pin SCSI II connector; the AUX I/O connector provides additional digital signal inputs/outputs with Event 1 - 4 (Pin 1 - 4) This connector outputs programmable timing signals generated by Markers 1 – 4; the marker signals can also routed internally to control the RF blanking and ALC hold functions This output is TTL and 3.3 V CMOS compatible; damage levels are > +8 V and < -4 V
USB 2.0	The USB connector provides remote programming functions via SCPI
LAN (1000 BaseT)	The LAN connector provides the same SCPI remote programming functionality as the GPIB connector and is also used to access the internal Web server and FTP server Supports DHCP, sockets SCPI, VXI-11 SCPI, connection monitoring, dynamic hostname services, TCP keep alive LXI class C compliant Trigger response time for the immediate LAN trigger is 0.5 ms (minimum), 4 ms (maximum), 2 ms, typical; delayed/alarm triger is unknown Trigger output response time is 0.5 ms (minimum), 4 ms (maximum), 2 ms, typical
GPIB	The GPIB connector provides remote programming functionality via SCPI

www.agilent.com www.agilent.com/find/EXG

Related Literature

Agilent X-Series Signal Generators

EXG Configuration Guide 5990-9958EN

MXG Data Sheet 5991-0038EN

MXG Configuration Guide 5990-9959EN

X-Series Signal Generator Brochure 5990-9957EN

Signal Studio Software Brochure 5989-6448EN



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